

Low Drop Voltage Regulator

TLE 4274



Features

- Output voltage 5 V, 8.5 V or 10 V
- Output voltage tolerance $\leq \pm 4\%$
- Current capability 400 mA
- Low-drop voltage
- Very low current consumption
- Short-circuit proof
- Reverse polarity proof
- · Suitable for use in automotive electronics
- Green Product (RoHS compliant) version of TLE 4274
- AEC qualified

Functional Description

The TLE 4274 is a low drop voltage regulator available in a TO220, TO252 and TO263 package. The IC regulates an input voltage up to 40 V to $V_{\text{Orated}} = 5.0$ V (V50), 8.5 V (V85) and 10 V (V10). The maximum output current is 400 mA. The IC is short-circuit proof and incorporates temperature protection that disables the IC at overtemperature. A 3.3 V and 2.5 V version is also available. For information about the low output voltage types please refer to the data sheet TLE 4274 / 3.3 V; 2.5 V.



PG-TO263-3-1

Туре	Package
TLE 4274 V10	PG-TO220-3-1 (RoHS compliant)
TLE 4274 V50	PG-TO220-3-1 (RoHS compliant)
TLE 4274 V85	PG-TO220-3-1 (RoHS compliant)
TLE 4274 DV50	PG-TO252-3-11 (RoHS compliant)
TLE 4274 GV10	PG-TO263-3-1 (RoHS compliant)
TLE 4274 GV50	PG-TO263-3-1 (RoHS compliant)
TLE 4274 GV85	PG-TO263-3-1 (RoHS compliant)



Dimensioning Information on External Components

The input capacitor $C_{\rm I}$ is necessary for compensating line influences. Using a resistor of approx. 1 Ω in series with $C_{\rm I}$, the oscillating of input inductivity and input capacitance can be damped. The output capacitor $C_{\rm Q}$ is necessary for the stability of the regulation circuit. Stability is guaranteed at values $C_{\rm Q} \ge 22 \ \mu\text{F}$ and an ESR of $\le 3 \ \Omega$ within the operating temperature range.

Circuit Description

The control amplifier compares a reference voltage to a voltage that is proportional to the output voltage and drives the base of the series transistor via a buffer. Saturation control as a function of the load current prevents any oversaturation of the power element. The IC also includes a number of internal circuits for protection against:

- Overload
- Overtemperature
- Reverse polarity







Table 1	Pin Definitions and Functions				
Pin No.	Symbol	Function			
1	I	Input; block to ground directly at the IC with a ceramic capacitor.			
2	GND	Ground			
3	Q	Output; block to ground with a \ge 22 μ F capacitor, ESR \le 3 Ω .			
ТАВ	-	TAB; connect to heatsink and GND to improve thermal performance			





Figure 2 Block Diagram



Table 2 Absolute Maximum Ratings

 $T_{\rm i}$ = -40 to 150 °C

Parameter	Symbol	Limit Values		Unit	Test Condition	
		Min.	Max.			
Input	4	1			1	
Voltage	V_1	-42	45	V	-	
Current	I	-	-	-	Internally limited	
Output						
Voltage	V_{Q}	-1.0	40	V	-	
Current	IQ	-	-	-	Internally limited	
Ground						
Current	$I_{\rm GND}$	-	100	mA	-	
Temperature						
Junction temperature	Tj	-	150	°C	-	
Storage temperature	T _{stg}	-50	150	°C	-	

Note: Maximum ratings are absolute ratings; exceeding any one of these values may cause irreversible damage to the integrated circuit.

Table 3Operating Range

Parameter	Symbol	Limit Values		Unit	Remarks
		Min.	Max.		
Input voltage; V50, DV50, GV50	VI	5.5	40	V	-
Input voltage, V85, GV85	$V_{\rm I}$	9.0	40	V	-
Input voltage, V10, GV10	$V_{\rm I}$	10.5	40	V	-
Junction temperature	Tj	-40	150	°C	-
Thermal Resistance					
Junction ambient	$R_{ m thja}$	-	65	K/W	TO220 ¹⁾
Junction ambient	R _{thja}	-	78	K/W	TO252 ¹⁾
Junction ambient	R _{thja}	-	52	K/W	TO263 ¹⁾
Junction case	R _{thjc}	-	4	K/W	-

 Worst case; regarding peak temperature, zero airflow mounted on PCB 80 × 80 × 1.5 mm³, 300 mm² heat sink area.



Table 4 Characteristics

V ₁ = 13.5 V; -40 °C < 7	i < 150 °C (unless	otherwise specified)
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Parameter	Symbol	Limit Values			Unit	Measuring Conditions
		Min. Typ. Max.				
Output voltage V50-Version	V _Q	4.8	5	5.2	V	$5 \text{ mA} < I_{\text{Q}} < 400 \text{ mA}$ $6 \text{ V} < V_{\text{I}} < 28 \text{ V}$
Output voltage V50-Version	V _Q	4.8	5	5.2	V	$5 \text{ mA} < I_{\text{Q}} < 200 \text{ mA}$ $6 \text{ V} < V_{\text{I}} < 40 \text{ V}$
Output voltage V85-Version	V _Q	8.16	8.5	8.84	V	$5 \text{ mA} < I_{\text{Q}} < 400 \text{ mA}$ $9.5 \text{ V} < V_{\text{I}} < 28 \text{ V}$
Output voltage V85-Version	V _Q	8.16	8.5	8.84	V	$5 \text{ mA} < I_{\text{Q}} < 200 \text{ mA}$ $9.5 \text{ V} < V_{\text{I}} < 40 \text{ V}$
Output voltage V10-Version	V _Q	9.6	10	10.4	V	5 mA < $I_{\rm Q}$ < 400 mA 11 V < $V_{\rm I}$ < 28 V
Output voltage V10-Version	V _Q	9.6	10	10.4	V	5 mA < $I_{\rm Q}$ < 200 mA 11 V < $V_{\rm I}$ < 40 V
Output current limitation ¹⁾	I _Q	400	600	-	mA	-
Current consumption; $I_q = I_l - I_Q$	Iq	-	100	220	μA	<i>I</i> _Q = 1 mA
Current consumption; $I_q = I_1 - I_Q$	I _q I _q	-	8 20	15 30	mA mA	$I_{\rm Q}$ = 250 mA $I_{\rm Q}$ = 400 mA
Drop voltage ¹⁾	V _{dr}	-	250	500	mV	$I_{\rm Q}$ = 250 mA $V_{\rm dr}$ = $V_{\rm l}$ - $V_{\rm Q}$
Load regulation	ΔV_{Q}	-	20	50	mV	$I_{\rm Q}$ = 5 mA to 400 mA
Line regulation	ΔV_{Q}	-	10	25	mV	$\Delta V_{\rm I}$ = 12 V to 32 V $I_{\rm Q}$ = 5 mA
Power supply ripple rejection	PSRR	-	60	-	dB	$f_{\rm r}$ = 100 Hz; $V_{\rm r}$ = 0.5 Vpp
Temperature output voltage drift	dV_Q/dT	-	0.5	-	mV/K	-

1) Measured when the output voltage $V_{\rm Q}$ has dropped 100 mV from the nominal value obtained at $V_{\rm I}$ = 13.5 V.













Typical Performance Characteristics (V50, V85 and V10)





Current Consumption I_q versus Output Current I_Q (high load)



Output Current I_Q versus Input Voltage V_1



Current Consumption I_q versus Output Current I_Q (low load)





Typical Performance Characteristics (V50)





Output Voltage Vo versus Input Voltage V_1





Input Current I₁ versus Input Voltage \dot{V}_{I}



Current Consumption I_q versus Input Voltage V₁



Typical Performance Characteristics for V85



Output Voltage V_{Q} versus Input Voltage V_{I}





Input Current I_1 versus Input Voltage V_1





Typical Performance Characteristics for V10





Output Voltage $V_{\rm Q}$ versus Input Voltage $V_{\rm I}$





Input Current I_1 versus Input Voltage V_1





Package Outlines





Green Product (RoHS-Compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

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SMD = Surface Mounted Device

Dimensions in mm





Figure 6 PG-TO252-3-11 (Plastic Transistor Single Outline)

Green Product (RoHS-Compliant)

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SMD = Surface Mounted Device

Dimensions in mm





Figure 7 PG-TO263-3-1 (Plastic Transistor Single Outline)

Green Product (RoHS-Compliant)

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SMD = Surface Mounted Device

Dimensions in mm



Revision History

Version	Date	Changes
Rev. 1.6	2007-02-16	Updated Infineon logo Added "AEC" and "Green" logo Added "Green Product" and "AEC qualified" to the feature list Added "Green Product" remark Updated Package Names to "PG-xxx" Removed leadframe variant "P-TO-252-1" Disclaimer Update
Rev. 1.7	2011-01-20	Added TAB potential to the package outline

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